NSN 5961-00-007-0736

Thyristor Semiconductor Device - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-007-0736 **Inclosure Material:** Metal **Overall Length:** 1.810 inches **Overall Diameter:** 1.227 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.062 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakover voltage, dc **Current Rating Per Characteristic:** 70.00 amperes source cutoff current **Power Rating Per Characteristic:** 15.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator: Terminal Type And Quantity:** 3 tab, solder lug **Specification Data:** 80131-release5386 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

NSN 5961-00-007-0736 Thyristor Semiconductor Device - Page 2 of 2



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